

GaAs MMIC EQUALIZER 2 - 18GHz

Features

Freq: 2~18GHz Slope: 2.7dB

Insertion Loss: 0.8dB@18GHz Chip Size: 0.79mm×0.75mm×0.1mm

General Description

The HG116JC is a GaAs pHEMT equalizer. Covering 2 to 18 GHz, this equalizer offers very high slope of 2.7dB and extremely low insertion loss of 0.8dB@18GHz. Input and output VSWR are 1.3/1.3.

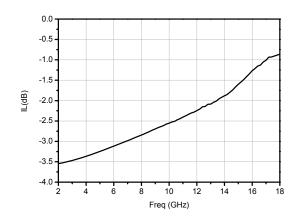
Electrical Specifications(T_A =25 \mathcal{C})

Parameter	Min.	Тур.	Max.
Frequency Range(GHz)		2∼18	
Input VSWR	-	1.3	-
Output VSWR	-	1.3	-
Insertion Loss(dB)	-	0.8~3.5	-
Slope(dB)	-	2.7	1

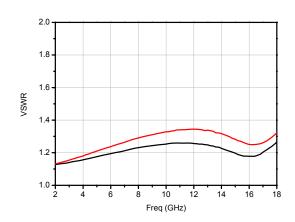
Absolute Maximum Ratings

3		
RF Input Power	+27dBm	
Operating Temperature	-55℃~125℃	
Storage Temperature	-65℃~150℃	

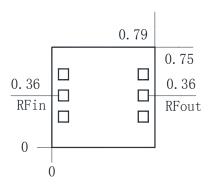
Insertion Loss



VSWR



Outline Drawing (mm)



Notes:

- 1. The chip should be stored in a dry and nitrogen environment, and used in a clean environment.
- 2. GaAs material is brittle, can not touch the surface of the chip, must be careful when using.
- 3. The chip is welding with conductive adhesive or alloy (alloy temperature should not exceed 300° C, and no more than 30 sec.), and should make it fully grounded.
- 4.The chip microwave port and substrate gap is not exceeding 0.05mm, with $\Phi25\mu m$ double gold wire bonding, suggested length of gold wire 250 $\sim\!400\mu m.$
- 5. Chip microwave port without DC blocking capacitor.
- 6. The chip is sensitive to static electricity, and should be protected against static electricity during storage and use.